



PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Docket No: Q78632

Toshio GOTO, et al.

Appln. No.: 10/578,835

Group Art Unit: unknown

Confirmation No.: 3740

Examiner: unknown

Filed: May 10, 2006

For: RADICAL GENERATING METHOD, ETCHING METHOD AND APPARATUS FOR

USE IN THESE METHODS

INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. §§ 1.97 and 1.98

MAIL STOP AMENDMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In accordance with the duty of disclosure under 37 C.F.R. § 1.56, Applicant hereby notifies the U.S. Patent and Trademark Office of the documents which are listed on the attached PTO/SB/08 A & B (modified) form and/or listed herein and which the Examiner may deem material to patentability of the claims of the above-identified application.

One copy of each of the listed documents is submitted herewith, except for the following: U.S. patents and/or U.S. patent publications; and co-pending non-provisional U.S. applications filed after June 30, 2003.

The present Information Disclosure Statement is being filed: (1) No later than three months from the application's filing date; (2) Before the mailing date of the first Office Action on the merits (whichever is later); or (3) Before the mailing date of the first Office Action after

INFORMATION DISCLOSURE STATEMENT U.S. Application No.: 10/578,835

Attorney Docket No. Q78632

filing a request for continued examination (RCE) under \$1.114, and therefore, no Statement

under 37 C.F.R. § 1.97(e) or fee under 37 C.F.R. § 1.17(p) is required.

In compliance with the concise explanation requirement under 37 C.F.R. § 1.98(a)(3) for

foreign language documents, Applicant submits the following explanations: The disclosure on

page 3 of the present specification and the submission of an English language abstract for

JP-A-11-145118 constitutes a concise statement of relevance of JP-A-11-145118.

The submission of the listed documents is not intended as an admission that any such

document constitutes prior art against the claims of the present application. Applicant does not

waive any right to take any action that would be appropriate to antedate or otherwise remove any

listed document as a competent reference against the claims of the present application.

The USPTO is directed and authorized to charge all required fees, except for the Issue

Fee and the Publication Fee, to Deposit Account No. 19-4880. Please also credit any

overpayments to said Deposit Account.

Respectfully submitted,

Registration No. 33,725

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23373 CUSTOMER NUMBER

Date: August 8, 2006

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Substitute for Form 1449 A & B/PTO

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

Sheet 1 of 1

Complete if Known				
Application Number	10/578,835			
Confirmation Number	3740			
Filing Date	May 10, 2006			
First Named Inventor	Toshio GOTO			
Art Unit	unknown			
Examiner Name	unknown			
Attorney Docket Number	Q78632			

			U.S. I	PATENT DOCU	MENTS
Examiner Initials*	Cite No. ¹	Document Number		Publication Date	
		Number	Kind Code ² (if known)	MM-DD-YYYY	Name of Patentee or Applicant of Cited Document
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Examiner Initials*	Cite No. ¹	Foreign Patent Document			Publication Date	Name of Patentee or	
		Country Code ³	Number ⁴	Kind Codes (if known)	MM-DD-YYYY	Applicant of Cited Document	Translation ⁶
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		NON PATENT LITERATURE DOCUMENTS				
Examiner Initials*	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city, and/or country where published.				
/RM/		TERUO SHIBANO, NOBUO FUJIWARA, MAKOTO HIRAYAMA, HITOSHI NAGATA, AND KIYOSHI DEMIZU; Eiching yields of SiO ₂ by low energy CF _X and F ⁺ ions; Appl. Phys. Lett. 63 (17), 25 October 1993, pages 2336-2338				
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^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Applicant's unique citation designation number (optional). "See Kind Codes of USPTO Patent Documents at www.uspto.gov, MPEP 901.04 or follow the hyperlink from the title of the document to the intranet." Enter Office that issued the document, by the two-letter code (WIPO Standard ST. 3). "For Japanese patent documents, the indication of the year of the reign of the Emperor mass precede the sextin number of the patent document. "Kind document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible." Applicant is similarlated here if English language Translation is attacked.